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INTRODUCTION
The isolation of graphene has provided an insight and excitement to explore other two-dimensional (2D) materials that go beyond graphene which include h-BN and transition metal dichalcogenides (TMDCs) such as MoS$_2$, WS$_2$, and WSe$_2$. The advent of such materials with intriguing properties has opened many avenues for their use in various applications such as transparent electrodes, sensors, flexible and stretchable transistors, logic circuits, light emitting diodes (LEDs), energy storage and energy conversion systems are dominated by vdW forces whereas it is non-transparent indeed wetting transparent to copper, gold and silicon and such systems are dominated by vdW forces whereas it is non-transparent to glass due to short range chemical bonding. The debate on intrinsic water contact angle on graphene came about when the effect of airborne contaminants on the wettability of graphene and graphite were shown by Li et al. Contrary to popular belief, it was found that the hydrophobic nature of graphene as reported by other groups was mostly due to hydrocarbons when the samples get exposed to ambient conditions. It was shown that thermal annealing and ultraviolet-O$_3$ treatment was effective in removing airborne contaminants and therefore graphene is intrinsically hydrophilic with WCA of 64.4° on HOPG and 59.6° for 2 to 3 layers of graphene on nickel. With sample ageing and exposure to ambient conditions the WCA showed hydrophobic value >90°. Similar study has been reported by Lai et al. where evolution of water wettability of graphene from hydrophilic to hydrophobic was shown. A nanoscopic approach using dynamic force spectroscopy
measurements using atomic force microscopy (AFM) has also been demonstrated.\(^7\) The first report on the study of surface energy of pristine monolayer graphene grown on copper substrates and aged graphene with exposure to ambient conditions by contact angle measurements and estimation of surface energy through Neumann and Owen, Wendt, Rabel and Kaelble (OWRK) models was reported by Kozbial \textit{et al.} showing that monolayer graphene is mildly polar\(^26\) which is surprising as graphene is supposed to be non-polar. The non-transparency of graphene has also been proved through static contact angle measurements and dynamic force spectroscopy studies using AFM.\(^26\) From all of these studies, it is clear that the surface wettability is greatly influenced by the surroundings. Changing the surrounding is clearly one of the ways to understand the surface wettability better.

Going beyond graphene, there are very few studies on the wetting properties of the other classes of 2D materials like graphene oxide, h-BN, TMDC etc. Perrozzi \textit{et al.} demonstrated the reduction dependent wetting properties of graphene oxide and reported the correlation between surface chemical composition and surface energy.\(^27\) Wetting behavior of WS\(_2\) and MoS\(_2\) on SiO\(_2\)/Si substrates grown by CVD has been studied where chalcogen (sulphur) substitution with oxygen resulted in hydrophobic to hydrophilic wettability transition.\(^28\) By varying the growth temperature, Gaur \textit{et al.} have demonstrated a change in the nature of the surface; from hydrophilic to hydrophobic as the temperature is increased clearly suggesting the extrinsic nature of the surface.\(^29\) The surface energy of highly crystalline few-layer thick MoS\(_2\) was found to be 46.5 mJ/m\(^2\).\(^29\) Recently, vdW heterostructures have been fabricated by stacking different 2D materials and in such structures covalent bonds provide in-plane stability and the vdW forces enable to keep the 2D stack together.\(^30\)-\(^32\) Most studies have focused on electrical properties and device applications in flexible/transparent electronics, optoelectronics, photonics etc., but to the best of our knowledge, there aren’t any reports on the wetting properties of such 2D heterostructures. The surface energy of an overlayer 2D material is influenced by the underlying substrate. That raises fundamental questions: what happens to the surface energy when a 2D material forms heterostructures with other 2D materials?

Motivated by such fundamental questions, we have investigated the wettability of graphene and graphene like layered TMDCs (MoS\(_2\) and WS\(_2\)) as individual and hybrid structures on h-BN and SiO\(_2\)/Si substrates. More specifically, the nature of surface free energy of the multilayer structures and the influence of the underlying substrate on the wettability of the overlayer has been studied exploring the effect of long range van der Waals interaction which is a less explored regime.

**Experimental**

**Contact angle and surface energy measurements**

The contact angle and surface energy measurements were carried out using the video based fully automated Data Physics optical contact angle microlitre dosing system (OCA 40 Micro). Solvent drops (1μl/drop) of DI water (more polar), ethylene glycol, formamide (intermediate polar & dispersive) and diiodomethane (mostly dispersive) with known surface tensions (refer SI Table 1) were dispensed using a Teflon coated motor driven syringe. The contact angles were measured at 22 °C and 45% RH conditions and a video was recorded (72 frames/second) for every dispensed solvent droplet. Any dynamic changes to the droplet on the surface can be precisely observed through this method. This system allows for estimation of contact angles with 0.1° accuracy. The contact angles with four different test liquids and surface free energies (polar and dispersive) were evaluated using the sessile drop technique and OWRK model respectively (refer SI).

**Atomic force microscopy**

The AFM images were obtained using JEOL JSPM 5200 with SiN probe tips of resonance frequency ~300 kHz and force constant ~40 N/m.

**Raman spectroscopy**

The Raman spectra of the 2D materials and their heterostructures have been recorded using a JY-Horiba LabRAM HR Evolution Raman spectrometer connected with an air-cooled charge coupled device (CCD) detector. The 514.5 nm line of an Ar-ion laser (Lexel 95-SHG Laser) has been used as an excitation source.

**Growth of MoS\(_2\) and WS\(_2\)**

High purity precursors of (NH\(_4\))\(_2\)MoS\(_4\) (Sigma Aldrich), (NH\(_4\))\(_2\)WS\(_4\) (Alfa Aesar) was dissolved in dimethyl formamide (DMF) solution and the solution was sonicated for 30 min. Prior to film preparation on a substrate, substrates were cleaned and treated with O\(_2\) plasma for 15 min. The prepared solution was then spin-coated on the substrates at 4000 rpm and was then baked on a hot plate at 150 °C for 10 min. To anneal the freshly prepared thin films, films were placed in the heat zone of the quartz tube with a gas flow mixture (Ar/H\(_2\)) at 1 Torr. This is followed by a two-step annealing process. The chamber was heated up to 400 °C at a heating rate of 5 °C/min and continued for 30 min to efficiently remove the residual solvent, NH\(_3\) molecules, and other by-products dissociated from the precursors. After the first annealing step, the gas environment was changed to Ar/H\(_2\)S at 1 Torr and the heat zone was heated up to 1000 °C at a heating rate of 20 °C/min and dwelled for 30 min.

**Growth of h-BN**

Hexagonal boron nitride (h-BN) nanosheets were synthesized by chemical vapor deposition (CVD) using borazine (B\(_3\)H\(_6\)N\(_3\)) as a precursor. The synthesis of the h-BN layer was carried out in a low pressure CVD system. For the growth process, a Cu-foil (Alfa Aesar, 125 μm-thick) was placed in the CVD chamber and gradually heated to 900 °C for 1 h in the presence of Ar (25 sccm) and H\(_2\) (25 sccm) gas flow to remove impurities. The temperature was then cooled down to 400 °C under the same condition. Once the temperature reached to 400 °C, 5 sccm borazine was injected with Ar gas flow for 15 min. Subsequently, the temperature was increased to 1000 °C with a dwell time of 1 hour. After an hour the chamber was cooled to room temperature.

**Preparation of heterostructures**

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\(^{28}\) By varying the growth temperature, Gaur \textit{et al.}\(^29\) demonstrated a change in the nature of the surface; from hydrophilic to hydrophobic as the temperature is increased clearly suggesting the extrinsic nature of the surface.\(^29\)

\(^{29}\) The surface energy of highly crystalline few-layer thick MoS\(_2\) was found to be 46.5 mJ/m\(^2\).\(^29\) Recently, vdW heterostructures have been fabricated by stacking different 2D materials and in such structures covalent bonds provide in-plane stability and the vdW forces enable to keep the 2D stack together.\(^30\)-\(^32\) Most studies have focused on electrical properties and device applications in flexible/transparent electronics, optoelectronics, photonics etc., but to the best of our knowledge, there aren’t any reports on the wetting properties of such 2D heterostructures.\(^30\)-\(^32\)

\(^{32}\) Motivated by such fundamental questions, we have investigated the wettability of graphene and graphene like layered TMDCs (MoS\(_2\) and WS\(_2\)) as individual and hybrid structures on h-BN and SiO\(_2\)/Si substrates. More specifically, the nature of surface free energy of the multilayer structures and the influence of the underlying substrate on the wettability of the overlayer has been studied exploring the effect of long range van der Waals interaction which is a less explored regime.
The single and hybrid structures were prepared by wet transfer method. In this method, poly methyl methacrylate (PMMA) was coated on as-grown MoS$_2$ and WS$_2$ and was baked for 10 min on a hotplate. Then, PMMA/WoS$_2$/SiO$_2$/Si and PMMA/MoS$_2$/SiO$_2$/Si substrates were put into BOE (Buffered Oxide Etch) solution for 30 min. PMMA/MoS$_2$ and PMMA/WoS$_2$ layers were transferred onto as-grown h-BN/Cu substrate. The sample was dipped in acetone to remove PMMA and the MoS$_2$/h-BN/Cu and WS$_2$/h-BN/Cu heterostructure/substrates were then baked for 15 min subsequently.

Results and discussion

2D materials and their heterostructures have been transferred on SiO$_2$/Si substrates, as described in the methods section, in order to investigate the nature of interaction between the layers, the surface wettability and surface energy of the overlayers. Fig. 1 (top panel) shows the AFM topography images and height statistical distribution (bottom panel) obtained on all samples used in this study. The wetting characteristics of a solid structure are found to be dependent on the roughness of its surface and such extrinsic influence is inherent to the fundamental wetting phenomena. The root mean square (RMS) roughness of all the fabricated samples are approximately few nanometers or less and therefore the effect of this extrinsic factor on the contact angle of these structures are insignificant. The quality of the 2D materials and their number of layers has been determined by Raman spectroscopy which is a nondestructive and noncontact technique. Fig. 2(a-d) shows the Raman spectra of all the fabricated samples used in this study. The Raman spectrum of graphene [Fig. 2(a)] consists of two unique signatures, namely, G-peak at ~1586 cm$^{-1}$ and 2D-peak at ~2685 cm$^{-1}$,

$\text{G-peak: } \Gamma_G \approx 21 \text{ cm}^{-1}, \text{ and } \Gamma_{2D} \approx 42 \text{ cm}^{-1}$,

and the intensity ratio of $I(G)/I(2D)$ = 0.19 whereas on h-BN, $\Gamma_G \approx 16 \text{ cm}^{-1}, \Gamma_{2D} \approx 37 \text{ cm}^{-1}$, and $I(G)/I(2D) = 0.66$. The linewidth and intensity ratio of the G-peak to the 2D-peak indicates the graphene to be a monolayer. Further, the very weak intensity of the D-peak at ~1350 cm$^{-1}$ is a clear indication of high quality graphene. On the other hand, the MoS$_2$ and WS$_2$ have unique in-plane ($E_g$) and out-of-plane ($A_{1g}$) vibrations arising from the relative motions of the Mo/W and S atoms. The difference in energy (frequency of vibration) of these two peaks identifies the number of layers being present. The heterostructures of the 2D materials being used in our experiments have a 4-layer thick MoS$_2$ and more than 5-layer thick WS$_2$ as suggested by their Raman spectra [see Fig. 2(b-d)]. Any appreciable energy shift in the Raman spectra of MoS$_2$ or WS$_2$ or their heterostructures was not observed. Further, their linewidth also do not show any appreciable broadening. Hence, we can rule out any possible substrate-induced doping on these samples. However, we could not observe any peak relating to h-BN, possibly due to its very low scattering cross-section. The number of layers of h-BN present in these structures was determined using transmission electron microscopy (TEM) and the obtained TEM image is shown in Fig. S3.

Fig. 3(a) is a schematic of vapor-liquid-solid interfaces where $\theta$, $\gamma_{lv}$, $\gamma_{sv}$, $\gamma_{sl}$, are contact angle, interfacial free energies of liquid/vapor, solid/vapor, solid/liquid respectively. The contact angle is related to interfacial energies through Young’s equation

$$\gamma_{lv}\cos\theta = \gamma_{sv} - \gamma_{sl} \tag{1}$$

Fig. 3(b) shows the measured water contact angles of the various 2D materials (graphene, MoS$_2$, WS$_2$) as well as their heterostructures. The images of the contact angles obtained using the other three test liquids (ethylene glycol, diiodomethane and formamide) and the measured contact angle values with error bar is shown in Fig. S4 and Table S2. The standard deviation has been calculated based on the variations in the measured left and right contact angles and also taking in to account the instrumental uncertainty of 0.1°. All the samples used in this study have been thermally annealed at 150 °C to remove any aromatic hydrocarbons and moisture that might be present on the surface before the contact angle measurements. A detailed study of the aromatic hydrocarbon contamination on graphite was recently reported by Martin et al. through Kelvin probe microscopy and it was shown that such contaminants desorb at 50 °C. The change in WCA of graphene on copper upon hydrocarbon contamination measured by ellipsometric phase shift was demonstrated. The contact angle of
Table 1. Data obtained from wetting measurements with four solvents and calculated surface energies of SiO$_2$/Si and BN/Cu.

<table>
<thead>
<tr>
<th>S/N</th>
<th>Sample Details</th>
<th>Water CA (degrees)</th>
<th>Ethylene Glycol CA (degrees)</th>
<th>Diodiodomethane CA (degrees)</th>
<th>Formamide CA (degrees)</th>
<th>Surface Energy Total (mN/m)</th>
<th>Surface Energy Polar (mN/m)</th>
<th>Surface Energy Dispersive (mN/m)</th>
<th>Convergence</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>SiO$_2$/Si</td>
<td>48.4±0.9</td>
<td>43.0±0.1</td>
<td>49.2±0.9</td>
<td>48.10±0.6</td>
<td>44.68</td>
<td>24.69</td>
<td>19.99</td>
<td>0.9129</td>
</tr>
<tr>
<td>2</td>
<td>BN/Cu</td>
<td>21.2±1.2</td>
<td>25.9±0.6</td>
<td>16.7±0.1</td>
<td>22.2±0.1</td>
<td>58.27</td>
<td>30.28</td>
<td>27.99</td>
<td>0.8597</td>
</tr>
</tbody>
</table>

Table 2. Calculated surface energies of the fabricated samples using the contact angles measured with four different solvents.

<table>
<thead>
<tr>
<th>S/N</th>
<th>Sample Details</th>
<th>Surface Energy Total (mN/m)</th>
<th>Surface Energy Polar (mN/m)</th>
<th>Surface Energy Dispersive (mN/m)</th>
<th>Convergence</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Graphene/h-BN/SiO$_2$/Si</td>
<td>36.69</td>
<td>3.45</td>
<td>33.24</td>
<td>0.9607</td>
</tr>
<tr>
<td>2</td>
<td>MoS$_2$/h-BN/SiO$_2$/Si</td>
<td>41.00</td>
<td>11.11</td>
<td>29.89</td>
<td>0.8202</td>
</tr>
<tr>
<td>3</td>
<td>WS$_2$/h-BN/SiO$_2$/Si</td>
<td>38.51</td>
<td>8.48</td>
<td>30.03</td>
<td>0.8453</td>
</tr>
<tr>
<td>4</td>
<td>MoS$_2$/WS$_2$/h-BN/SiO$_2$/Si</td>
<td>41.64</td>
<td>8.65</td>
<td>32.98</td>
<td>0.8556</td>
</tr>
<tr>
<td>5</td>
<td>Graphene/SiO$_2$/Si</td>
<td>34.68</td>
<td>1.53</td>
<td>33.15</td>
<td>0.9811</td>
</tr>
<tr>
<td>6</td>
<td>MoS$_2$/SiO$_2$/Si</td>
<td>34.87</td>
<td>5.87</td>
<td>28.99</td>
<td>0.9429</td>
</tr>
<tr>
<td>7</td>
<td>WS$_2$/SiO$_2$/Si</td>
<td>39.19</td>
<td>5.51</td>
<td>33.68</td>
<td>0.9067</td>
</tr>
<tr>
<td>8</td>
<td>MoS$_2$/WS$_2$/SiO$_2$/Si</td>
<td>39.48</td>
<td>0.31</td>
<td>39.16</td>
<td>0.9240</td>
</tr>
</tbody>
</table>

A sample can be invariably restored and obtained over several runs of measurements after simple thermal annealing to remove any adsorbed molecules on the surface and hence the reproducibility in measurements is ensured [refer to Table S2].

In 2D structures, the in-plane atoms are covalently bonded and the interlayer coupling is through vdW interactions. From Tables 1 & 2, it is clear that these vdW structures are not fully wetting transparent to the underlying substrate as the substrate does influence the surface wettability of these structures. We made sure, that each material (graphene, MoS$_2$ and WS$_2$) on the two different platforms were of same thickness (see Fig. 2) in order to make a comparison on the wetting and henceforth the influence of the underlying substrate on the wettability. Samples deposited on h-BN shows higher wettability when compared to samples of same thickness on SiO$_2$/Si substrates. For example, the hybrid structure of MoS$_2$ and WS$_2$ on h-BN shows a water contact angle of 89.9° degrees whereas this hybrid structure with exactly the same thickness on SiO$_2$/Si shows a water contact angle of 63.3°. This could be attributed to the water contact angle of these underlying systems. This study also provides information about the long range nature of the forces involved in the wettability which essentially allows the substrate surface energy to influence 4 to 5 layer MoS$_2$ or WS$_2$ systems.

Table 1 summarizes the results of contact angle measurements obtained with four different solvents on SiO$_2$/Si and h-BN/Cu. From Table 1, it can be seen that h-BN is more wettable and has higher total surface energy when compared to SiO$_2$/Si. Kozbial et al. reported that graphene is intrinsically mildly polar although it has non-polar sp$^2$ structure and suggest that the mild polarity could be due to π hydrogen bonding and/or surface defects leading to partial wetting transparency. Our studies show that the surface wettability of both graphene and graphene-like layered TMDCs is predominantly influenced by the wettability of the underlying substrate and this is attributed to its partial wetting transparency.

In order to compute the surface free energy of a solid surface ($\gamma_{sv}$), the other two energies which include the solid/liquid interface free energy ($\gamma_{sl}$) and liquid/vapor interface free energy ($\gamma_{lv}$) in the Young’s equation must be known. Clearly, $\gamma_{sv}$ is known from liquid surface tension. However, $\gamma_{sl}$ is an unknown variable.
based on solid surface tension ($y_{sv}$), liquid surface tension ($y_{lv}$) and the interactions between two phases. As per Fowkes method, these interactions can be interpreted as the geometric mean of a dispersive and polar component of surface tensions $y^D$ and $y^P$ respectively. The solid/liquid interfacial energy can be written as:

$$y_{sl} = y_{sv} + y_{lv} - 2\left(y_{s\ell}^D y_{l\ell}^P + y_{s\ell}^P y_{l\ell}^D\right) \quad (2)$$

Therefore, two or more liquids with known polar and dispersive components are used to find the solid surface free energy using OWRK model.\(^{45}\) The OWRK method separates the interfacial surface tension according to the underlying interactions (polar and dispersive) between the molecules. Hence, the total surface energy of the solid is the sum of polar and dispersive components. The polar component originates from the permanent dipole-dipole interactions. They are stronger in polar molecules (having permanent dipole moment). On the other hand, the dispersive component arises due to random fluctuations in the electron density when brought together, leading to an induced dipole-dipole interaction (London-vdW forces or London dispersion forces). The detailed description of OWRK model and fitting results are shown in SI. Importantly, the convergence factor (indicated in Table 2) is close to $-1$, showing this model is very suitable to calculate surface energies of vdW structures with a high degree of accuracy.

Fig. 4 shows the surface energy plots of all the fabricated samples fitted using OWRK model and the corresponding surface energy values computed are shown in Table 2. The contact angles obtained on the fabricated 2D structures with four test liquids (water, ethylene glycol, diiodomethane and formamide) and the repeatability in water contact angle (water CA repeat) values which were obtained after thermal annealing at 150 °C before every measurement cycle to eliminate the aromatic hydrocarbons and adsorbed water if any is shown in Table S2. The samples were not affected by this mild annealing protocol and we followed the procedure usually adopted in electrical measurements. For example, annealing at 400 K recovers the intrinsic surface of graphene/BN system as evident from the zero charge neutrality point. At this annealing condition, oxidation of MoS\(_2\) and WS\(_2\) samples was not introduced as well. Any presence of MoO\(_3\) should be reflected as a strong Raman peak at ~820 cm\(^{-1}\). In our Raman data of MoS\(_2\), we have not observed any peak at 820 cm\(^{-1}\). So, we can rule out the oxidation process at 150 °C. A Raman spectrum of MoS\(_2\) after 150 °C annealing showing absence of any peak near 820 cm\(^{-1}\) is shown in Fig. S6. Moreover from the XPS spectral response, Donarelli et al. reported that 150 °C annealed MoS\(_2\) samples were very much identical to as prepared samples and the MoS\(_2\) was not significantly altered by mild annealing at 150 °C.\(^7\)

The total surface energy values of these structures range from 34 mN/m to 42 mN/m out of which the polar contributions are ~few mN/m. From the surface energy estimations, it is found that all the vdW individual and hybrid structures studied have intrinsically highly dispersive surfaces and this is attributed to the long range London dispersion forces. VdW interactions are an important component of surface forces in these systems. Due to the highly dispersive nature of these surfaces, the classical approach based on Lifshitz and Hamakeron London dispersion forces can be applied and these systems do not require a non-pairwise additive theory where Keesom (force between two permanent dipoles) and Debye (force between a permanent and a corresponding induced dipole) contribution of polar interactions are significant.\(^{46}\) However, a small increase in the polar component of the surface energy may be noticed when the 2D materials or their heterostructures are placed on h-BN platform. The increase may be due to the polar nature of the underlying h-BN inducing a partial polar character to the overlayer (2D materials/heterostructure). While looking at the structure of these fabricated materials, h-BN, graphene, MoS\(_2\) and WS\(_2\) invariably possess hexagonal lattice structure.\(^{47-49}\) While h-BN has highly polar B-N bonds, graphene, MoS\(_2\) and WS\(_2\) exhibit predominant non-polar bonds. Graphene has homonuclear C-C intralayer bonds and the bonds in such homonuclear diatomic molecules are non-polar.\(^{47-49}\) MoS\(_2\) crystal consists of S-Mo-S sandwiches where S and Mo atoms are held together by covalent bonds.\(^{49}\) Two surfaces originate from the rupture of vdW interactions (face) and covalent bonds (edge).\(^{49}\) The face ([0001] plane) generated by the rupture of vdW forces gives the material a non-polar surface. The surface (edge) created by the covalent bonds tend to be hydrophilic.\(^{49}\) But the wettability in this material is strongly influenced by the vdW interactions, giving it a dispersive nature. WS\(_2\) also belongs to the same family of layered TMDCs as MoS\(_2\) and consists of S-W-S sandwiches. The edge structures of WS\(_2\) are [10\(\overline{1}0\)] w-edge and [\(\overline{1}010\)] s-edge.\(^{49}\)

**Conclusions**

We have explored the wettability of vdW based individual and hybrid structures. Our measurements clearly show that the 2D materials are not totally wetting transparent but there is measurable influence of the underlying substrate on the wettability making them partially wetting transparent. From surface energy calculations it is found that invariably the major class of 2D materials which include graphene, MoS\(_2\), WS\(_2\) possess dispersive surfaces. However, these 2D materials when placed on h-BN, reveal a non-negligible polar component perhaps induced by the polar nature of the underlying h-BN. We believe our work will help the scientific community to further understand the fundamentals of...
liquid-solid interactions in the exciting class of 2D materials and pave the way for future applications involving solid/liquid interfaces.

Acknowledgements

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References

22. T. Young, Phil. Trans. R. Soc. Lon., 1805, 95, 65-87.
25. G. J. Hirasaki, SPE-17367-PA, DOI: 10.2118/17367-PA.